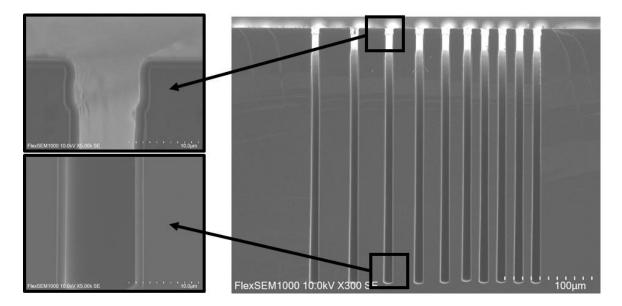


~ 400 nm SiO<sub>2</sub> deposited at 180 cycles per minute on trench with overhanging aperture. ~500 nm of  $Ta_2O_5$  was previously deposited using conventional pulsed ALD, to provide image contrast and narrow aperture.



 $1.2\mu$  SiO<sub>2</sub> deposited at 120 cycles per minute on trenches with 10 $\mu$  width and 300 $\mu$  depth. ~150 nm of Ta<sub>2</sub>O<sub>5</sub> was previously deposited using conventional pulsed ALD to provide image contrast.